

V_{DSS}	600V
$R_{DS(on)}$ (Max.)	1.2Ω
I_D	6A
P_D	40W

●Features

- 1) Low on-resistance.
- 2) Fast switching speed.
- 3) Gate-source voltage (V_{GSS}) guaranteed to be ±30V.
- 4) Drive circuits can be simple.
- 5) Parallel use is easy.
- 6) Pb-free lead plating ; RoHS compliant

●Application

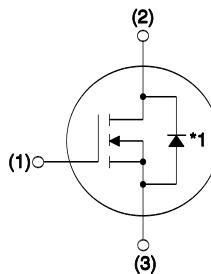
Switching Power Supply

●Outline

TO-220FM



●Inner circuit



(1) Gate
(2) Drain
(3) Source

*1 Body Diode

●Packaging specifications

Type	Packing	Bulk
	Reel size (mm)	-
	Tape width (mm)	-
	Basic ordering unit (pcs)	500
	Taping code	-
	Marking	R6006ANX

●Absolute maximum ratings ($T_a = 25^\circ\text{C}$)

Parameter	Symbol	Value	Unit
Drain - Source voltage	V_{DSS}	600	V
Continuous drain current	I_D *1	±6	A
	I_D *1	±2.9	A
Pulsed drain current	$I_{D,pulse}$ *2	±24	A
Gate - Source voltage	V_{GSS}	±30	V
Avalanche energy, single pulse	E_{AS} *3	2.4	mJ
Avalanche energy, repetitive	E_{AR} *4	1.9	mJ
Avalanche current	I_{AR} *3	3	A
Power dissipation ($T_c = 25^\circ\text{C}$)	P_D	40	W
Junction temperature	T_j	150	°C
Range of storage temperature	T_{stg}	-55 to +150	°C
Reverse diode dv/dt	dv/dt *5	15	V/ns

●Absolute maximum ratings

Parameter	Symbol	Conditions	Values	Unit
Drain - Source voltage slope	dv/dt	$V_{DS} = 480V$, $I_D = 6A$ $T_j = 125^\circ C$	50	V/ns

●Thermal resistance

Parameter	Symbol	Values			Unit
		Min.	Typ.	Max.	
Thermal resistance, junction - case	R_{thJC}	-	-	3.125	°C/W
Thermal resistance, junction - ambient	R_{thJA}	-	-	70	°C/W
Soldering temperature, wavesoldering for 10s	T_{sold}	-	-	265	°C

●Electrical characteristics ($T_a = 25^\circ C$)

Parameter	Symbol	Conditions	Values			Unit
			Min.	Typ.	Max.	
Drain - Source breakdown voltage	$V_{(BR)DSS}$	$V_{GS} = 0V$, $I_D = 1mA$	600	-	-	V
Drain - Source avalanche breakdown voltage	$V_{(BR)DS}$	$V_{GS} = 0V$, $I_D = 6A$	-	700	-	V
Zero gate voltage drain current	I_{DSS}	$V_{DS} = 600V$, $V_{GS} = 0V$ $T_j = 25^\circ C$ $T_j = 125^\circ C$	-	0.1	100	μA
Gate - Source leakage current	I_{GSS}	$V_{GS} = \pm 30V$, $V_{DS} = 0V$	-	-	± 100	nA
Gate threshold voltage	$V_{GS(th)}$	$V_{DS} = 10V$, $I_D = 1mA$	2.5	-	4.5	V
Static drain - source on - state resistance	$R_{DS(on)}^{*6}$	$V_{GS} = 10V$, $I_D = 3A$ $T_j = 25^\circ C$ $T_j = 125^\circ C$	-	0.9	1.2	Ω
Gate input resistance	R_G	f = 1MHz, open drain	-	7.6	-	Ω

●Electrical characteristics ($T_a = 25^\circ\text{C}$)

Parameter	Symbol	Conditions	Values			Unit
			Min.	Typ.	Max.	
Transconductance	g_{fs}^{*6}	$V_{DS} = 10\text{V}, I_D = 3.0\text{A}$	1.7	3.5	-	S
Input capacitance	C_{iss}	$V_{GS} = 0\text{V}$ $V_{DS} = 25\text{V}$ $f = 1\text{MHz}$	-	520	-	pF
Output capacitance	C_{oss}		-	380	-	
Reverse transfer capacitance	C_{rss}		-	25	-	
Effective output capacitance, energy related	$C_{o(er)}$	$V_{GS} = 0\text{V}$ $V_{DS} = 0\text{V to } 480\text{V}$	-	25	-	pF
Effective output capacitance, time related	$C_{o(tr)}$		-	25	-	
Turn - on delay time	$t_{d(on)}^{*6}$	$V_{DD} \approx 300\text{V}, V_{GS} = 10\text{V}$ $I_D = 3\text{A}$ $R_L = 100\Omega$ $R_G = 10\Omega$	-	22	-	ns
Rise time	t_r^{*6}		-	18	-	
Turn - off delay time	$t_{d(off)}^{*6}$		-	50	100	
Fall time	t_f^{*6}		-	35	70	

●Gate Charge characteristics ($T_a = 25^\circ\text{C}$)

Parameter	Symbol	Conditions	Values			Unit
			Min.	Typ.	Max.	
Total gate charge	Q_g^{*6}	$V_{DD} \approx 300\text{V}$	-	15	-	nC
Gate - Source charge	Q_{gs}^{*6}	$I_D = 6\text{A}$ $V_{GS} = 10\text{V}$	-	4	-	
Gate - Drain charge	Q_{gd}^{*6}		-	6	-	
Gate plateau voltage	$V_{(plateau)}$	$V_{DD} \approx 300\text{V}, I_D = 6\text{A}$	-	6.0	-	V

*1 Limited only by maximum temperature allowed.

*2 PW ≤ 10μs, Duty cycle ≤ 1%

*3 L ≈ 500μH, $V_{DD} = 50\text{V}$, $R_G = 25\Omega$, starting $T_j = 25^\circ\text{C}$

*4 L ≈ 500μH, $V_{DD} = 50\text{V}$, $R_G = 25\Omega$, starting $T_j = 25^\circ\text{C}$, f = 10kHz

*5 Reference measurement circuits Fig.5-1.

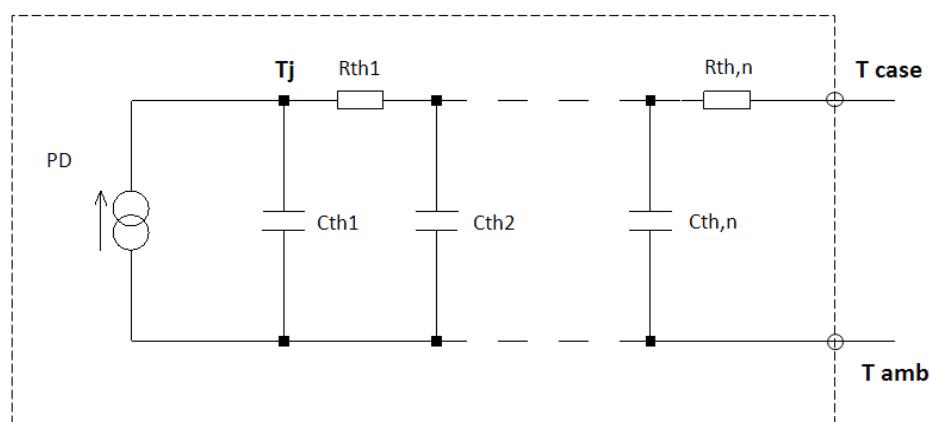
*6 Pulsed

● Body diode electrical characteristics (Source-Drain) ($T_a = 25^\circ\text{C}$)

Parameter	Symbol	Conditions	Values			Unit
			Min.	Typ.	Max.	
Inverse diode continuous, forward current	I_S^{*1}	$T_c = 25^\circ\text{C}$	-	-	6	A
Inverse diode direct current, pulsed	I_{SM}^{*2}		-	-	24	A
Forward voltage	V_{SD}^{*6}	$V_{GS} = 0\text{V}, I_S = 6\text{A}$	-	-	1.5	V
Reverse recovery time	t_{rr}^{*6}	$I_S = 6\text{A}$ $dI/dt = 100\text{A}/\mu\text{s}$	-	302	-	ns
Reverse recovery charge	Q_{rr}^{*6}		-	2.0	-	μC
Peak reverse recovery current	I_{rrm}^{*6}		-	13	-	A
Peak rate of fall of reverse recovery current	di_{rr}/dt	$T_j = 25^\circ\text{C}$	-	300	-	$\text{A}/\mu\text{s}$

● Typical Transient Thermal Characteristics

Symbol	Value	Unit	Symbol	Value	Unit
R_{th1}	0.342	K/W	C_{th1}	0.00138	Ws/K
R_{th2}	1.15		C_{th2}	0.0146	
R_{th3}	2.19		C_{th3}	0.452	



●Electrical characteristic curves

Fig.1 Power Dissipation Derating Curve

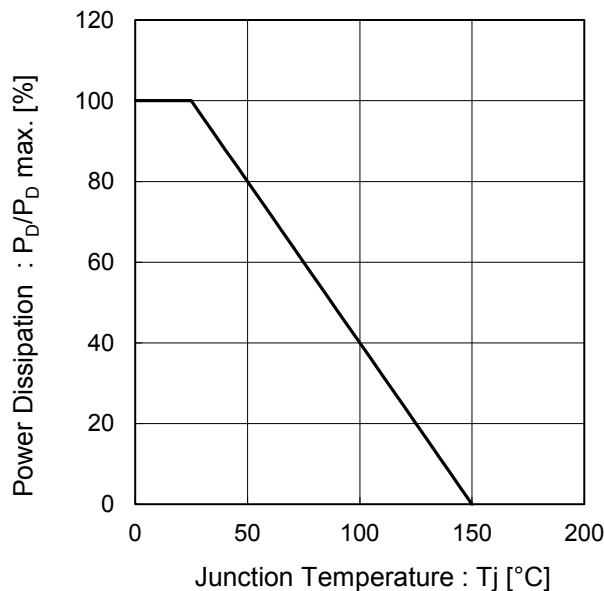


Fig.2 Maximum Safe Operating Area

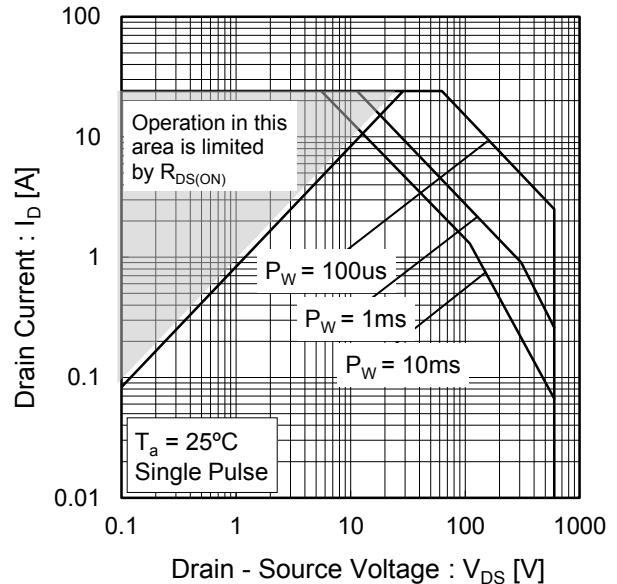
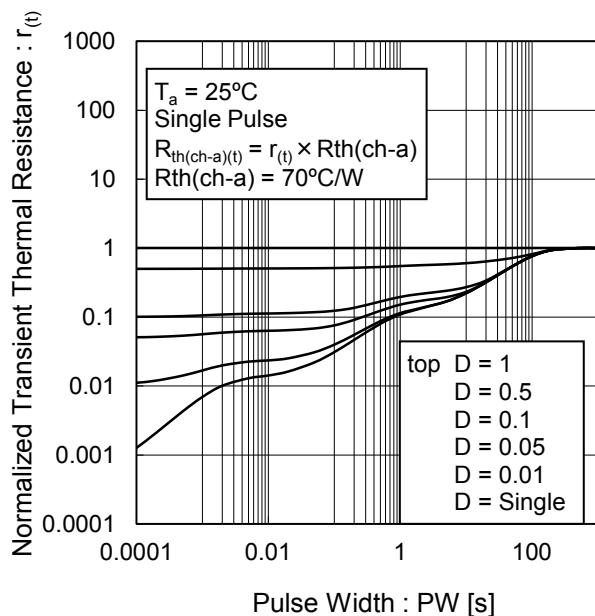


Fig.3 Normalized Transient Thermal Resistance vs. Pulse Width



●Electrical characteristic curves

Fig.4 Avalanche Current vs Inductive Load

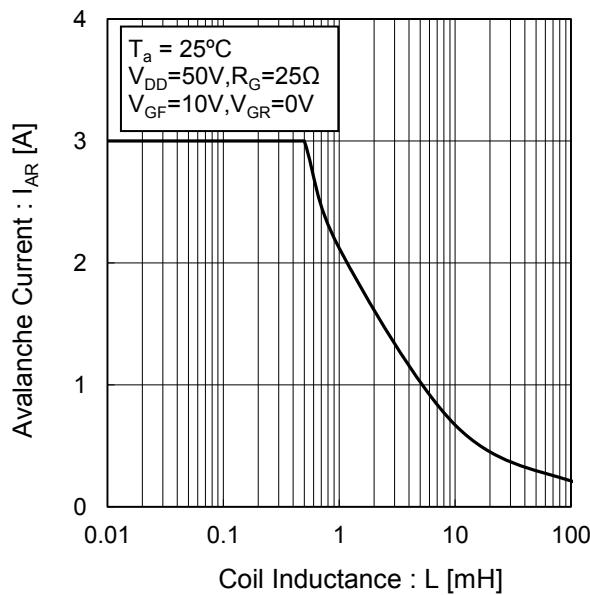


Fig.5 Avalanche Power Losses

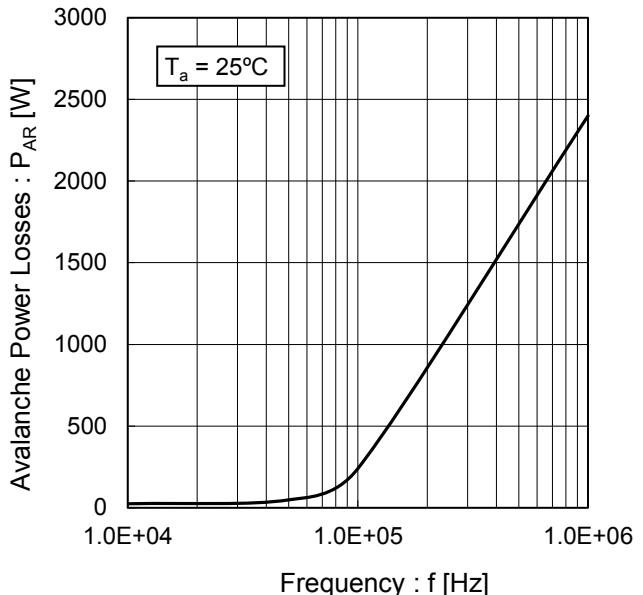
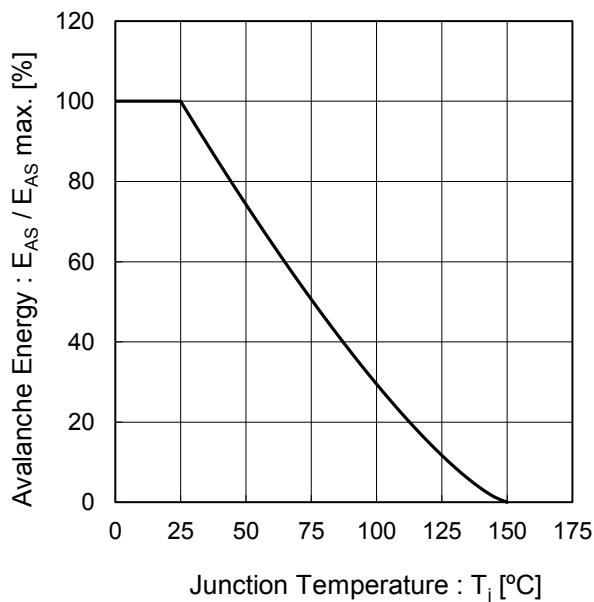


Fig.6 Avalanche Energy Derating Curve
vs Junction Temperature



●Electrical characteristic curves

Fig.7 Typical Output Characteristics(I)

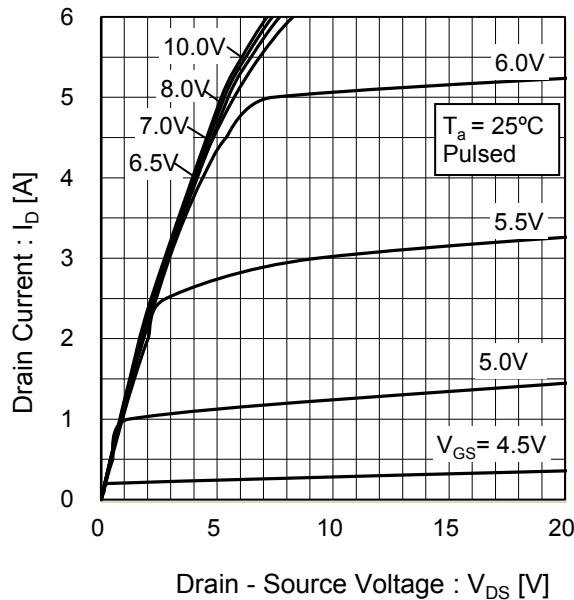


Fig.8 Typical Output Characteristics(II)

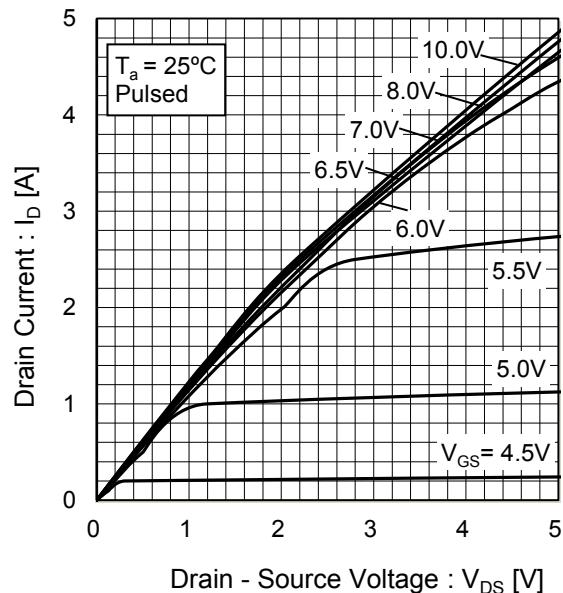


Fig.9 $T_j = 150^\circ\text{C}$ Typical Output Characteristics(I)

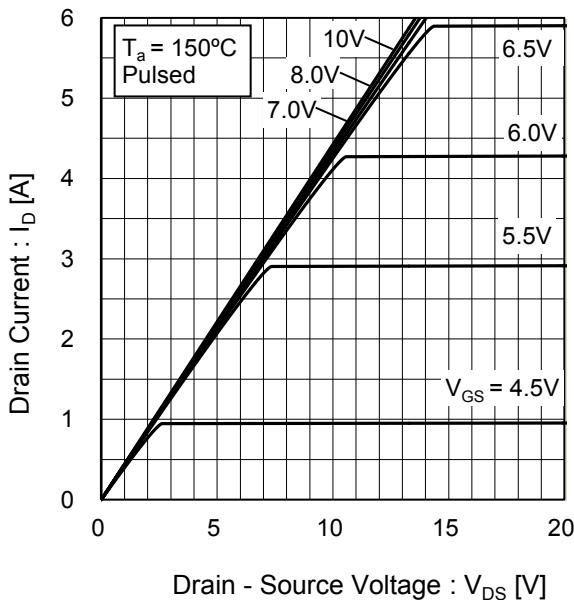
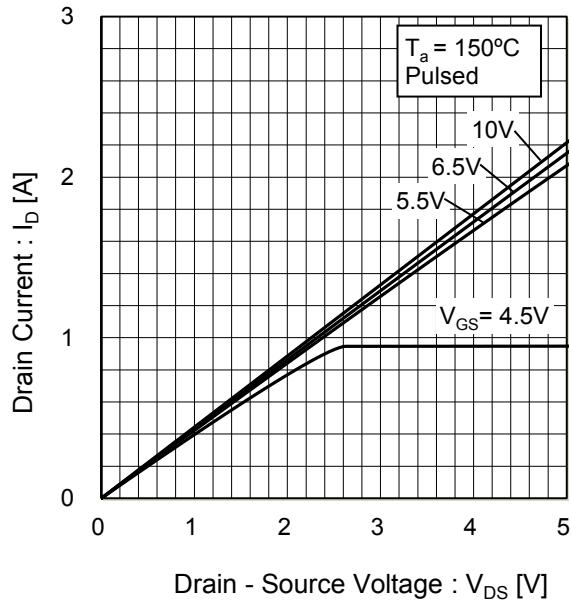


Fig.10 $T_j = 150^\circ\text{C}$ Typical Output Characteristics(II)



●Electrical characteristic curves

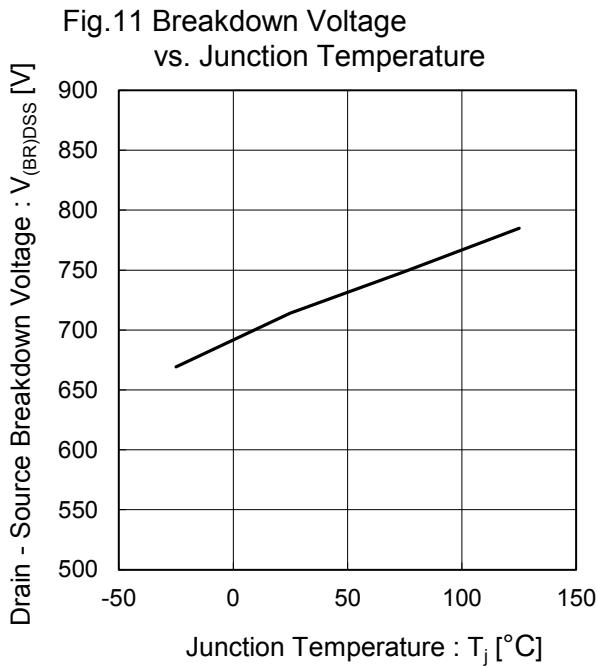


Fig.12 Typical Transfer Characteristics

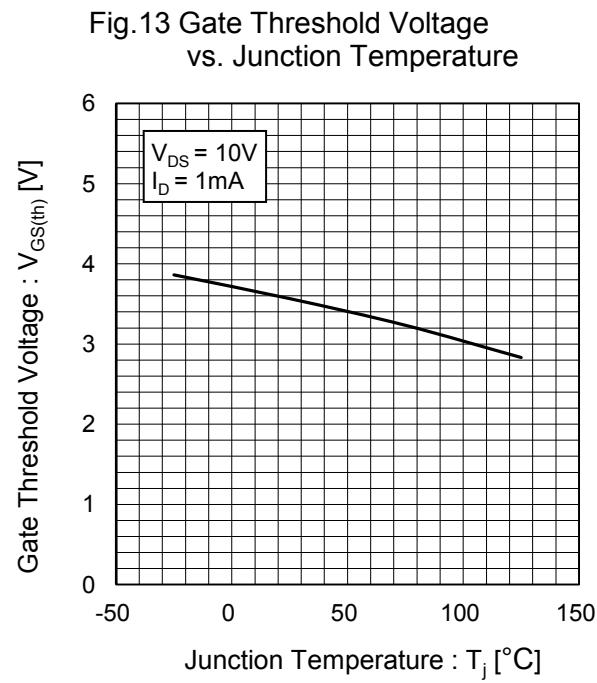
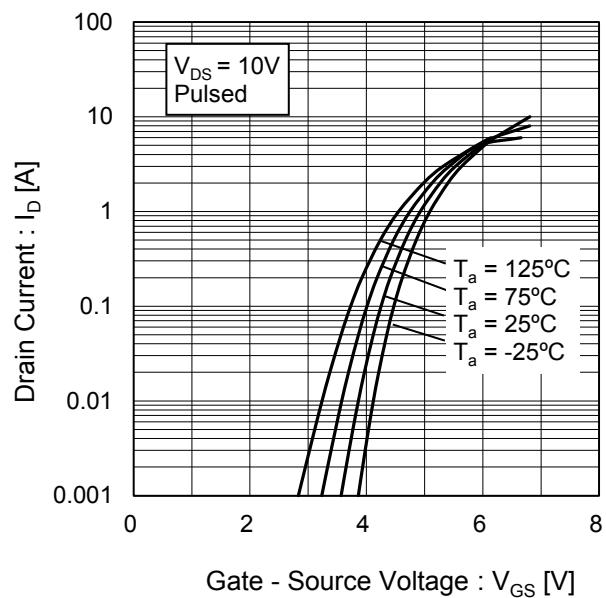
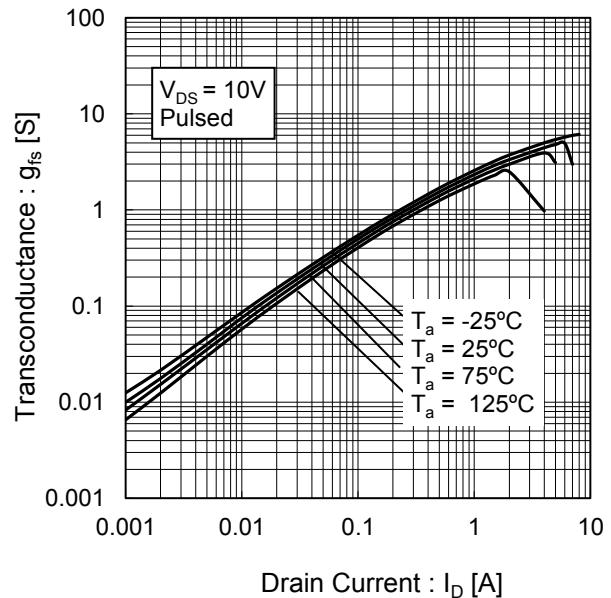


Fig.14 Transconductance vs. Drain Current



●Electrical characteristic curves

Fig.15 Static Drain - Source On - State Resistance vs. Gate Source Voltage

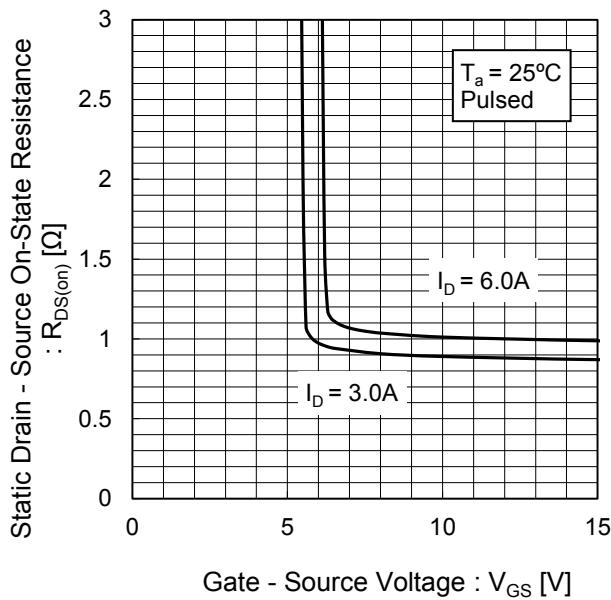


Fig.16 Static Drain - Source On - State Resistance vs. Junction Temperature

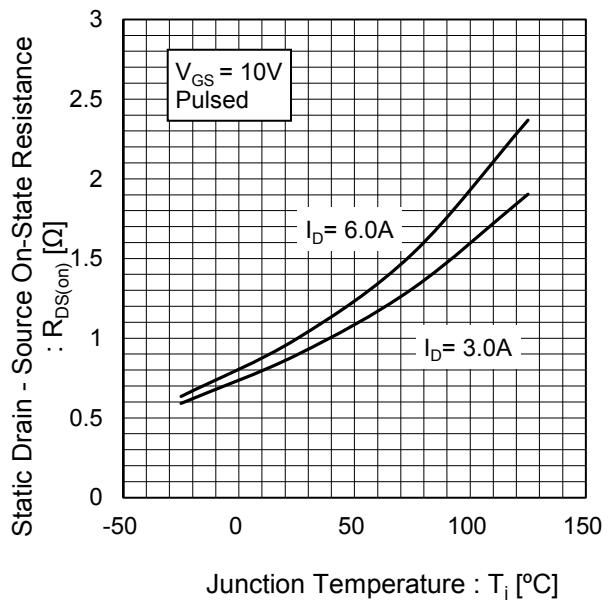
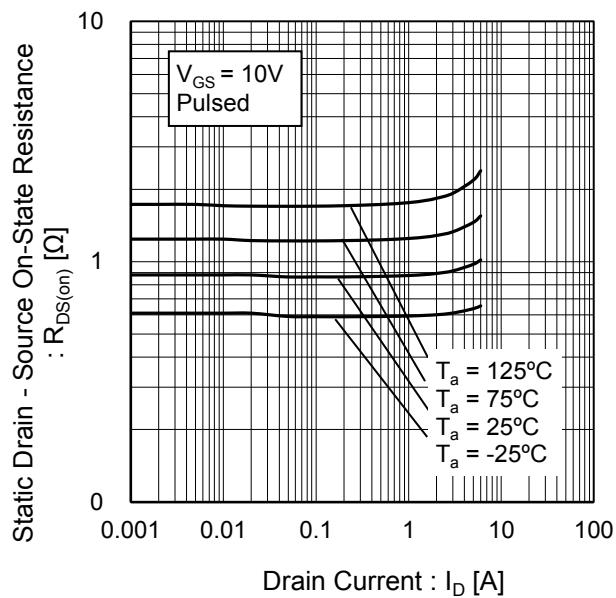


Fig.17 Static Drain - Source On - State Resistance vs. Drain Current



●Electrical characteristic curves

Fig.18 Typical Capacitance vs. Drain - Source Voltage

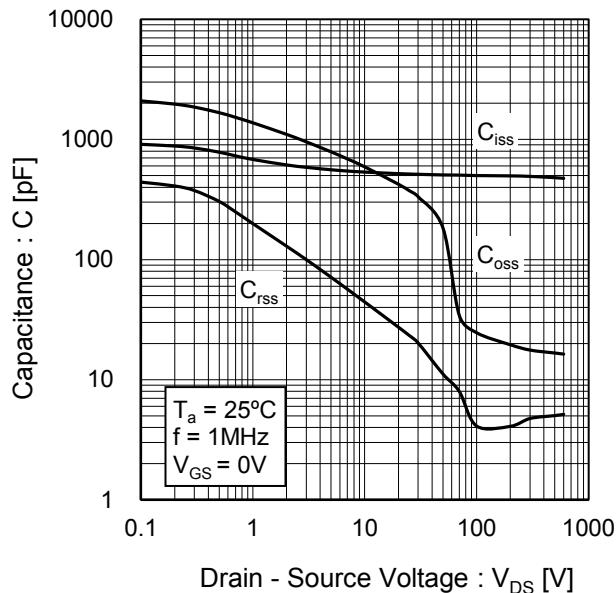


Fig.19 Coss Stored Energy

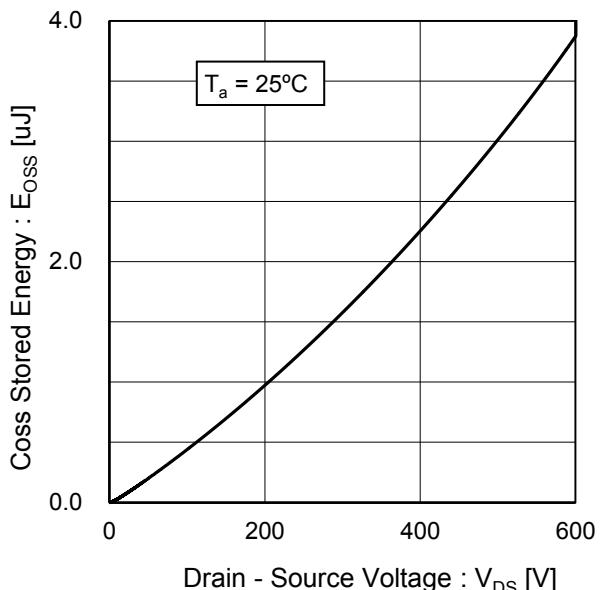


Fig.20 Switching Characteristics

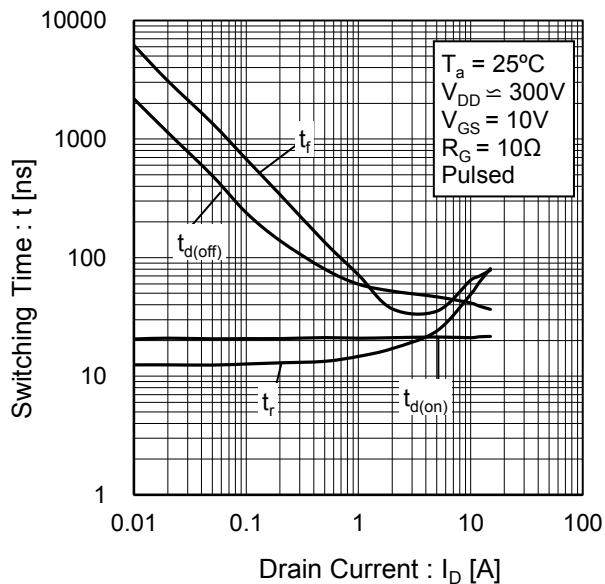
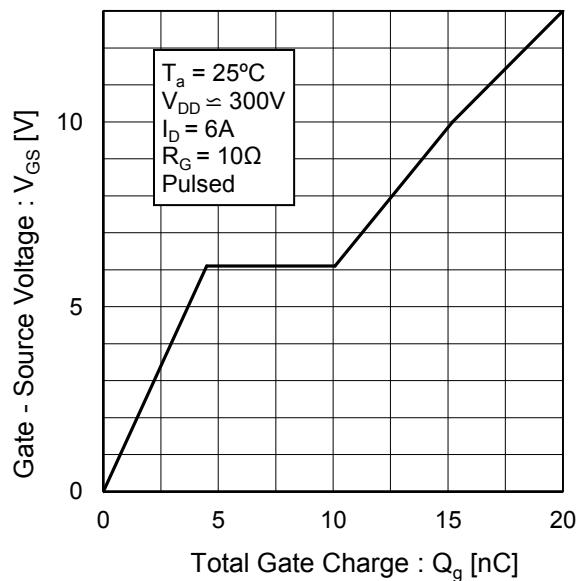
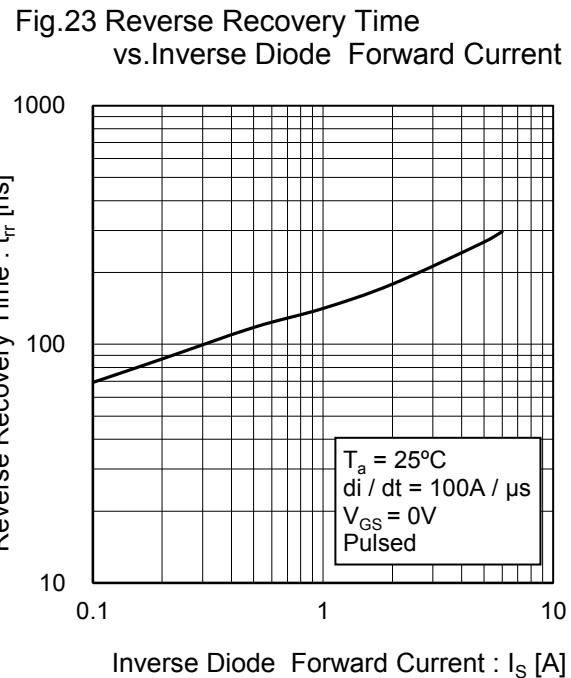
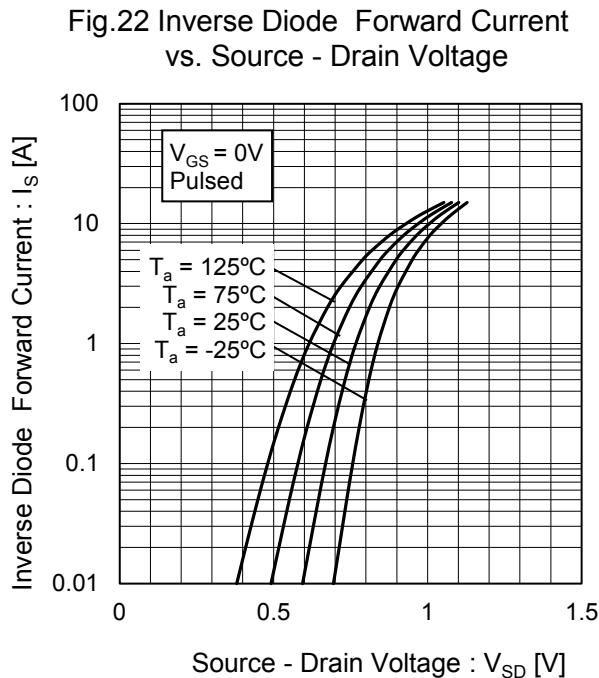


Fig.21 Dynamic Input Characteristics



●Electrical characteristic curves



● Measurement circuits

Fig.1-1 Switching Time Measurement Circuit

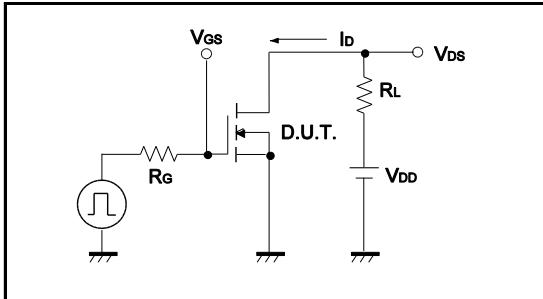


Fig.1-2 Switching Waveforms

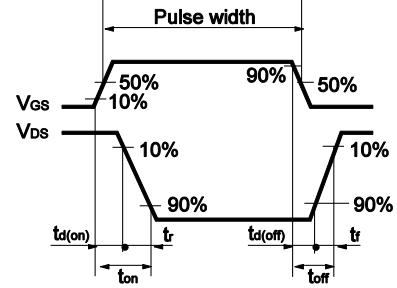


Fig.2-1 Gate Charge Measurement Circuit

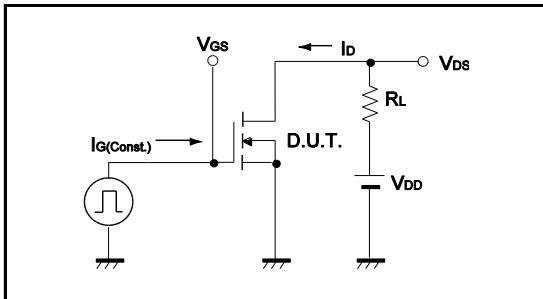


Fig.2-2 Gate Charge Waveform

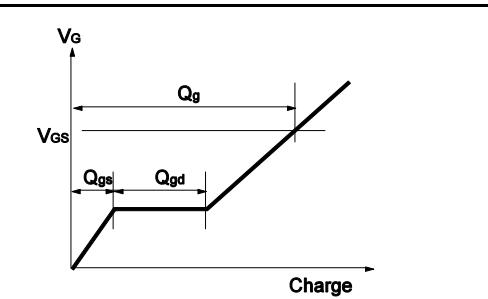


Fig.3-1 Avalanche Measurement Circuit

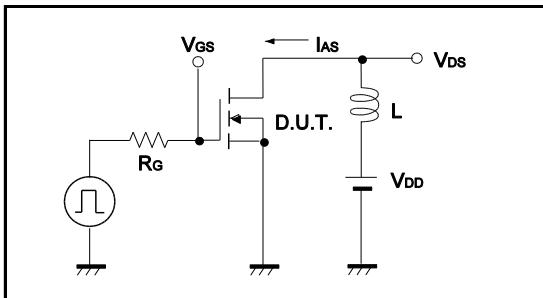


Fig.3-2 Avalanche Waveform

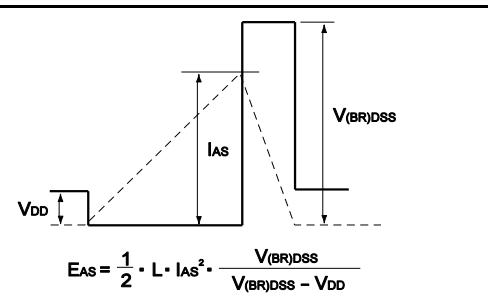


Fig.4-1 dv/dt Measurement Circuit

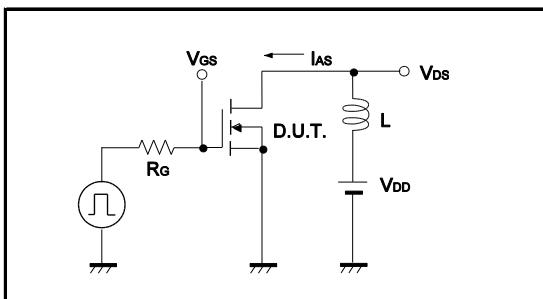


Fig.4-2 dv/dt Waveform

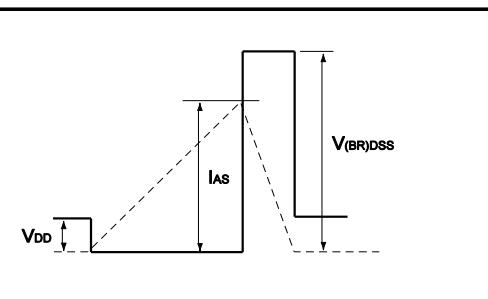


Fig.5-1 di/dt Measurement Circuit

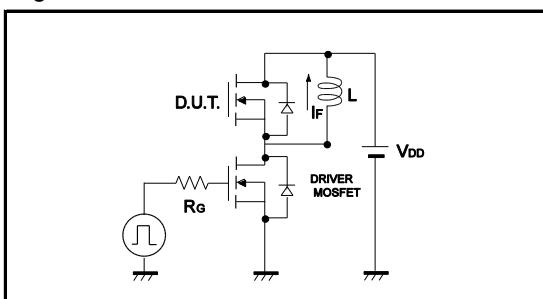
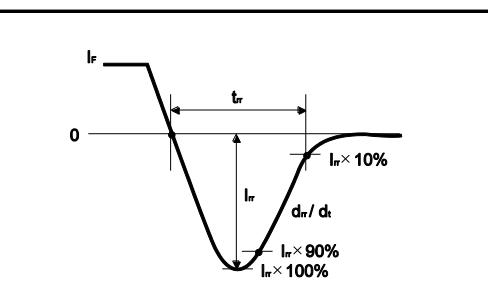
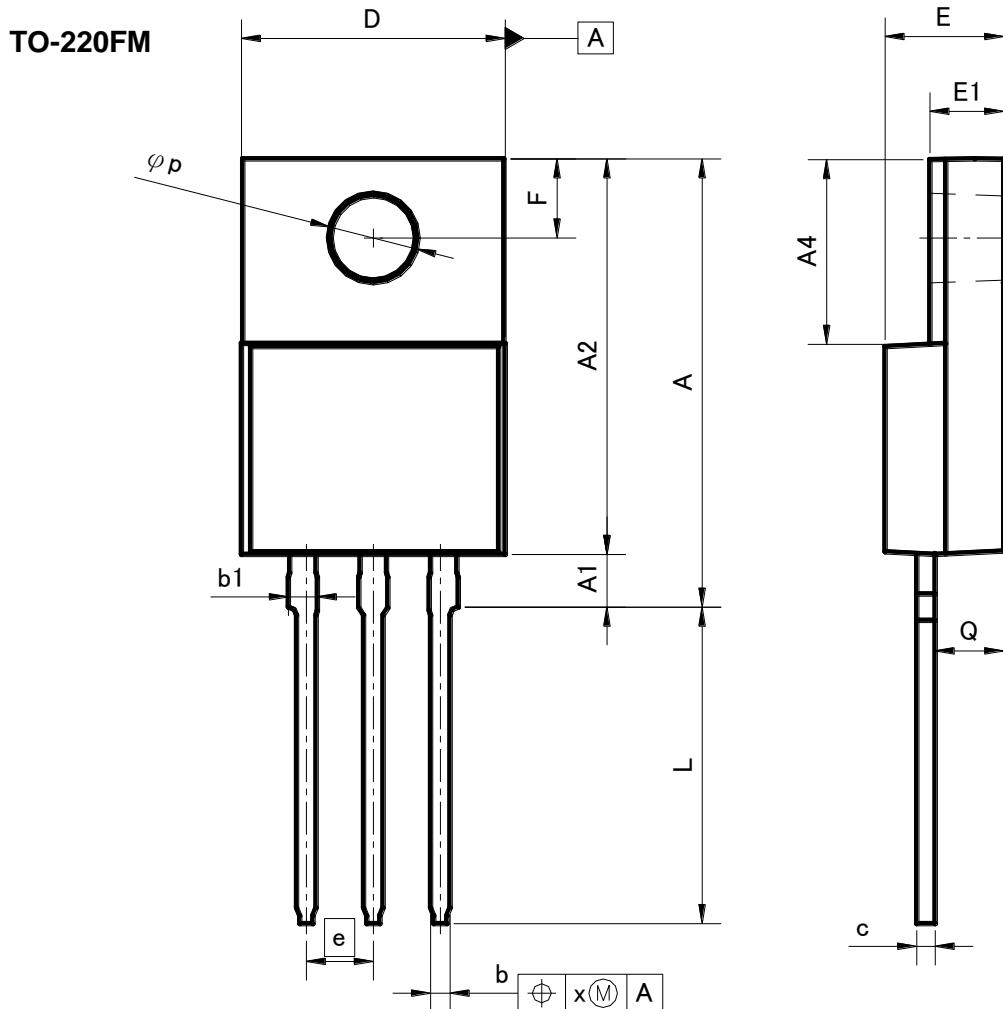


Fig.5-2 di/dt Waveform



●Dimensions (Unit : mm)



DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	16.60	17.60	0.654	0.693
A1	1.80	2.20	0.071	0.087
A2	14.80	15.40	0.583	0.606
A4	6.80	7.20	0.268	0.283
b	0.70	0.85	0.028	0.033
b1	1.10	1.50	0.043	0.059
c	0.70	0.85	0.028	0.033
D	9.90	10.30	0.39	0.406
E	4.40	4.80	0.173	0.189
e	2.54		0.10	
E1	2.70	3.00	0.106	0.118
F	2.80	3.20	0.11	0.126
L	11.50	12.50	0.453	0.492
p	3.00	3.40	0.118	0.134
Q	2.10	3.10	0.083	0.122
x	-	0.381	-	0.015

Dimension in mm/inches

Notes

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